

40V N-Channel Enhancement Mode MOSFET

Voltage

Current 45 A

Features

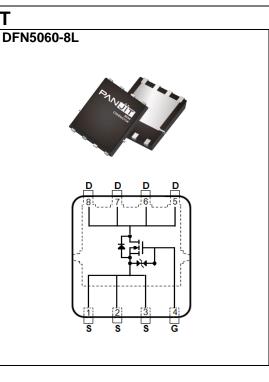
• $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<10m\Omega$

40 V

- $R_{DS(ON)}$, $V_{GS}@7V$, $I_D@10A<12.4m\Omega$
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|---|----------------------|------------------|---------|-------|--|
| Drain-Source Voltage | | V _{DS} | 40 | V | |
| Gate-Source Voltage | | V _{GS} | ±20 | | |
| Continuous Drain Current ^(Note 3) | T _C =25°C | | 45 | | |
| | Tc=100°C | I _D | 32 | А | |
| Pulsed Drain Current ^(Note 1) | T _C =25°C | I _{DM} | 180 | | |
| Power Dissipation | T _C =25°C | De | 36 | 14/ | |
| | Tc=100°C | PD | 18 | W | |
| Continuous Drain Current ^(Note 4) | T _A =25°C | | 13.6 | | |
| | T _A =70°C | I _D | 11.4 | — A | |
| Power Dissipation | T _A =25°C | Da | 3.3 | 14/ | |
| | T _A =70°C | PD | 2.3 | W | |
| Single Pulse Avalanche Energy ^(Note 5) | | Eas | 42 | mJ | |
| Operating Junction and Storage Temperature Range | | TJ,TSTG | -55~175 | °C | |
| Thermal Resistance ^(Note 4) | Junction to Case | $R_{\theta JC}$ | 4.2 | °C/W | |
| | Junction to Ambient | R _{θJA} | 45 | C/W | |



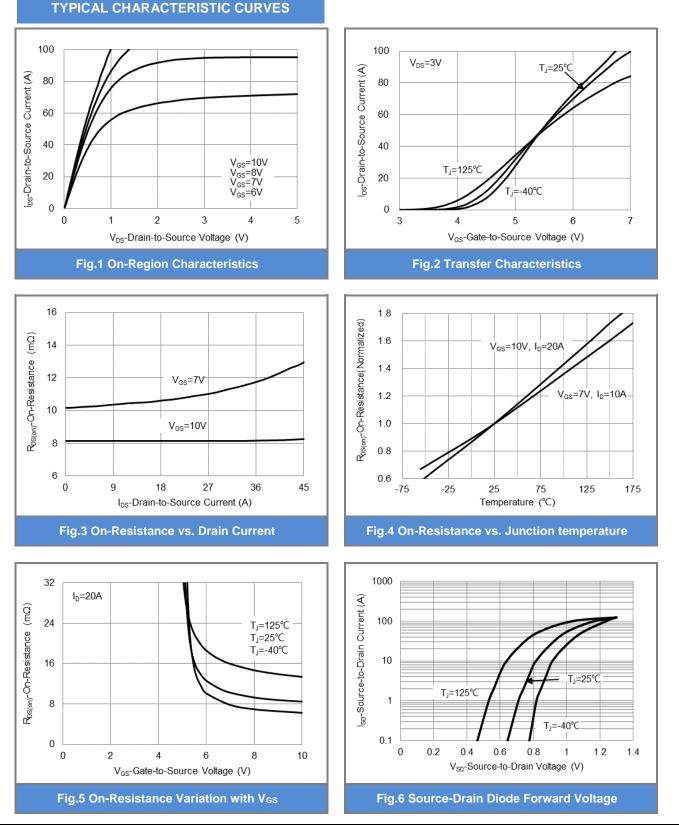
Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|--|------|------|------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250uA | 40 | - | - | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =50uA | 2 | 2.8 | 3.5 | V |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =20A | - | 8 | 10 | mΩ |
| | | V _{GS} =7V, I _D =10A | - | 9.5 | 12.4 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =40V, V_{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±10 | - uA |
| | | V _{GS} =±10V, V _{DS} =0V | - | - | ±1 | |
| Dynamic ^(Note 6) | _ | | | - | - | _ |
| Total Gate Charge | Qg | V _{DS} =32V, I _D =20A, V _{GS} =10V | - | 9.5 | - | nC |
| Gate-Source Charge | Qgs | | - | 4.2 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 2.6 | - | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, f=1MHz | - | 673 | - | pF |
| Output Capacitance | Coss | | - | 176 | - | |
| Reverse Transfer Capacitance | Crss | | - | 29 | - | |
| Gate resistance | Rg | f=1MHz | - | 1.4 | - | Ω |
| Turn-On Delay Time | td _(on) | V _{DS} =32V, I _D =20A, V _{GS} =10V, R _G =3Ω (Note 2) | - | 13 | - | ns |
| Turn-On Rise Time | tr | | - | 85 | - | |
| Turn-Off Delay Time | td(off) | | - | 17 | - | |
| Turn-Off Fall Time | tf | | - | 38 | - | |
| Drain-Source Diode | | | | | | |
| Diode Forward Current | Is | Tc=25°C | - | - | 45 | A |
| Pulsed Diode Forward Current | I _{SM} | 10=20 U | - | - | 180 | |
| Diode Forward Voltage | V _{SD} | Is=20A, V _{GS} =0V | - | 0.9 | 1.3 | V |
| Reverse Recovery Time | Trr | V _{GS} =0V, I _S =20A | - | 24 | - | ns |
| Reverse Recovery Charge | Qrr | dI _S /dt=100A/us | - | 14 | - | nC |

NOTES :

- 1. Pulse width<100us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}$ =4.2°C/W.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. The test condition is L=0.5mH, I_{AS}=13A, V_{DD}=30V, V_{GS}=10V, Starting T_J=25^{\circ}C.
- 6. Guaranteed by design, not subject to production testing.

January 30,2023



PANJ SEM CONDUCTOR

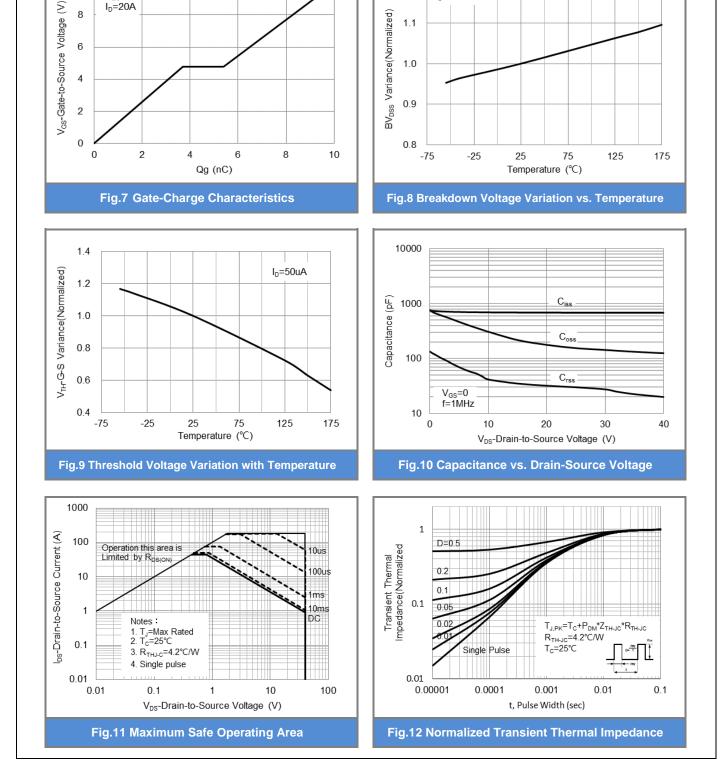
PJQ5548V-AU



January 30,2023

PJQ5548V-AU-REV.00

Page 4



1.2

1.1

1.0

I_D=250uA

TYPICAL CHARACTERISTIC CURVES

PJQ5548V-AU

V_{DS}=32V

I_D=20A

PANJ SEM CONDUCTOR

10

8

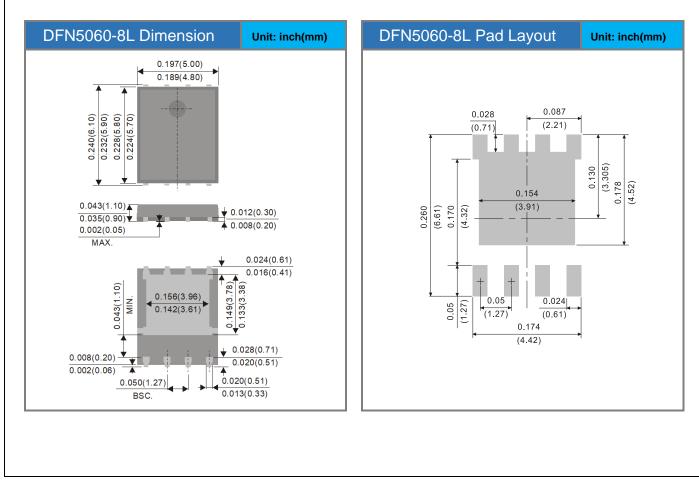
6



Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|-------------------|---------|--------------------------------|
| PJQ5548V-AU_R2_002A1 | DFN5060-8L | 3K pcs / 13" reel | Q5548V | Halogen free RoHS compliant |

Packaging Information & Mounting Pad Layout





Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.